



Features

- UL recognition, file #E476985
- Glass passivated chip
- High surge current capability
- Low thermal resistance
- Solder dip 275 °C max. 7 s, per JESD 22-B106

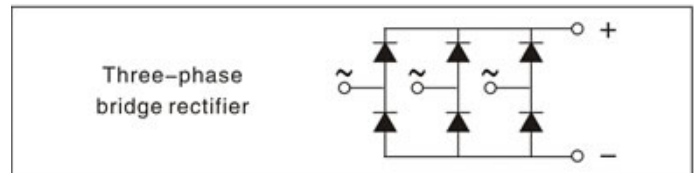
Typical Applications

General purpose use in AC/DC bridge full wave rectification for power supply, home appliances, office equipment, industrial automation applications.



Mechanical Data

- **Package:** MT
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102



■ Maximum Ratings ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MT5004T	MT5006T	MT5008T	MT5010T	MT5012T	MT5014T	MT5016T
Device marking code			MT5004T	MT5006T	MT5008T	MT5010T	MT5012T	MT5014T	MT5016T
Repetitive Peak Reverse Voltage	VRRM	V	400	600	800	1000	1200	1400	1600
Average Rectified Output Current @60Hz sine wave, R-load, With heatsink, $T_c=55^\circ\text{C}$	I_O	A	50						
Surge(Non-repetitive)Forward Current @60Hz Half- sine Wave, 1 cycle, $T_a=25^\circ\text{C}$	IFSM	A	500						
Current Squared Time @1ms $\leq t \leq$ 8.3ms $T_j=25^\circ\text{C}$, Rating of per diode	I^2t	A ² S	1040						
Storage Temperature	T_{stg}	$^\circ\text{C}$	-55~+150						
Junction Temperature	T_j	$^\circ\text{C}$	-55~+150						
Dielectric Strength, Terminals to case, AC 1 minute	Vdis	KV	2.5						
Mounting Torque	TOR	kg-cm	10						

■ Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MT5004T	MT5006T	MT5008T	MT5010T	MT5012T	MT5014T	MT5016T
Maximum instantaneous forward voltage drop per diode	VFM	V	$I_{FM}=25\text{A}$	1.2						
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM	μA	$V_{RM}=V_{RRM}$	10						

■ Thermal Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MT5004T	MT5006T	MT5008T	MT5010T	MT5012T	MT5014T	MT5016T
Thermal Resistance Between junction and case, With heatsink	$R_{\theta J-C}$	$^\circ\text{C}/\text{W}$	0.88						



■ Characteristics (Typical)

FIG1:Io-Tc Curve

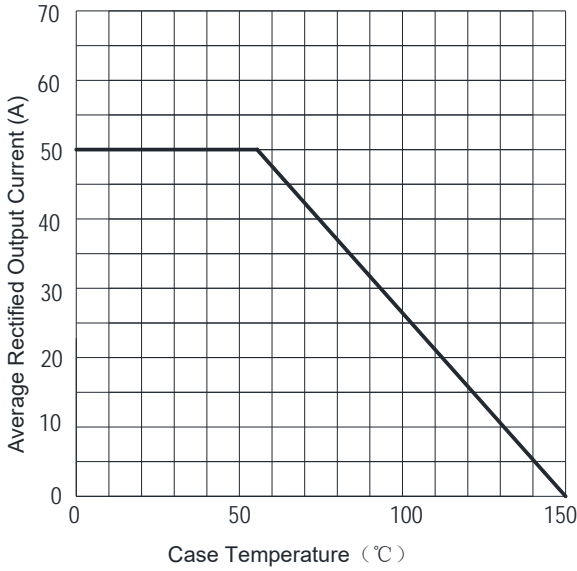


FIG2:Surge Forward Current Capability

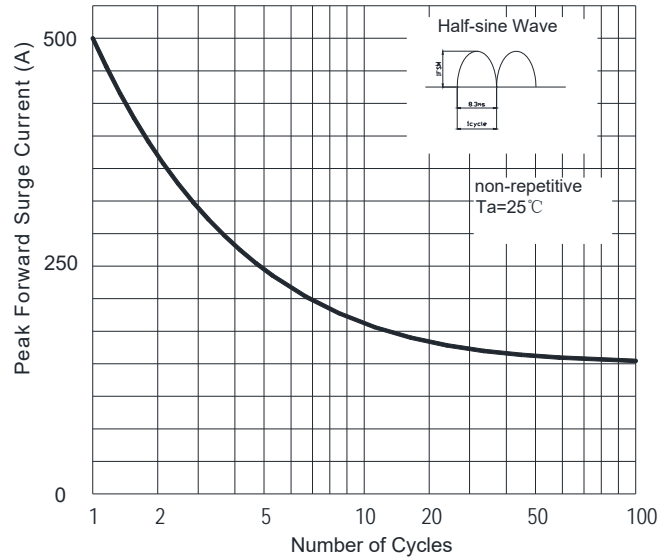


FIG3:Instantaneous Forward Voltage

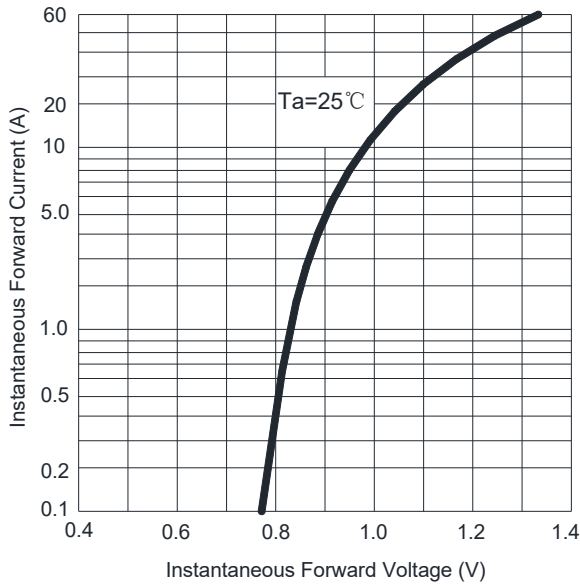
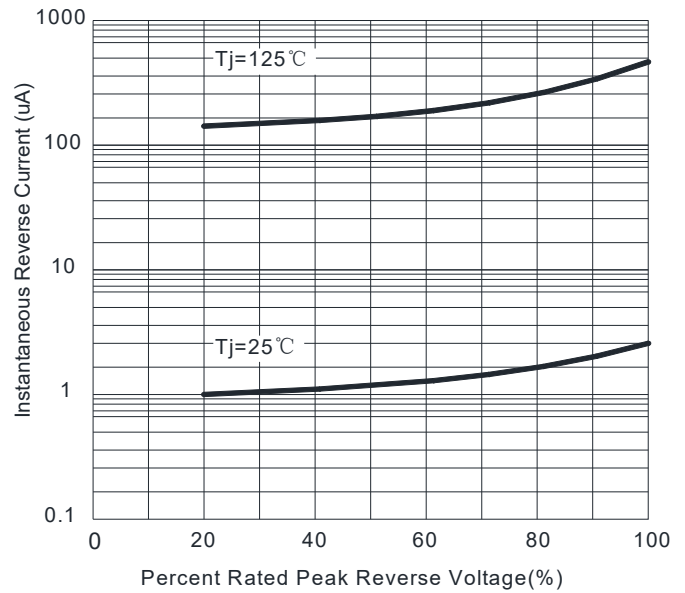


FIG4:Typical Reverse Characteristics





■ Outline Dimensions

MT

